NSN 5961-01-016-1936

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-016-1936 **Inclosure Material:** Glass **Overall Length:** Between 0.145 inches and 0.175 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.068 inches and 0.076 inches **End Application:** Spruance class dd (963); austin ship class lpd-4 amphibious transport docks; airborne mobile dir air spt ctl (21d), (02 jul 83) (an/uyq-3a); virginia class cgn (41); t-akr 310 class; forrestal class cv; sirius class t-afs 8; defense communications radio (9 systems); ticonderoga class cg (47); tactical air opns module (an/tyg (23) **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 300.0 reverse voltage, peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Weapon system essential **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No